TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74AC10P,TC74AC10F,TC74AC10FN

#### Triple 3-Input NAND Gate

The TC74AC10 is an advanced high speed CMOS 3-INPUT NAND GATE fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

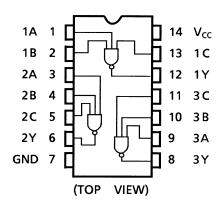
#### Features

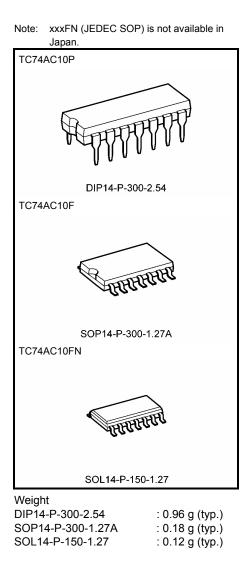
- High speed:  $t_{pd} = 5.0$  ns (typ.) at  $V_{CC} = 5$  V
- Low power dissipation:  $I_{CC} = 4 \mu A (max)$  at  $Ta = 25^{\circ}C$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Symmetrical output impedance: |IOH| = IOL = 24 mA (min)

Capability of driving 50 Ω transmission lines.

- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: VCC (opr) = 2 to 5.5 V
- Pin and function compatible with 74F10

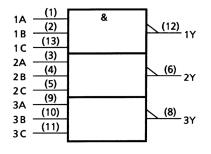
# **Pin Assignment**





# <u>TOSHIBA</u>

#### **IEC Logic Symbol**



#### **Truth Table**

А	В	С	Y
L	Х	Х	Н
Х	L	Х	Н
Х	Х	L	Н
Н	Н	Н	L

X: Don't care

# Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	–0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	Vout	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	lık	±20	mA
Output diode current	I <sub>ОК</sub>	±50	mA
DC output current	IOUT	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±100	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T <sub>stg</sub>	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

# **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V	
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V	
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V	
Operating temperature	T <sub>opr</sub>	-40 to 85	°C	
Input rise and fall time	dt/dV	0 to 100 (V_{CC} = 3.3 $\pm$ 0.3 V)	ns/V	
	uvuv	0 to 20 (V_{CC} = 5 $\pm$ 0.5 V)	115/ V	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

# **Electrical Characteristics**

#### **DC Characteristics**

Characteristics Symbol		Test Condition V <sub>CC</sub> (V)			Ta = 25°C			Ta = -40 to 85°C		Unit		
						Min	Тур.	Max	Min	Max	Offic	
		_		2.0	1.50	_	_	1.50	_	v		
High-level input voltage	VIH			3.0	2.10	—	—	2.10	—			
					5.5	3.85	—	_	3.85	_		
					2.0		—	0.50		0.50		
Low-level input voltage	VIL		—		3.0	—	—	0.90	—	0.90	V	
ů,				5.5	—	—	1.65	—	1.65			
	V <sub>OH</sub>				2.0	1.9	2.0	_	1.9	_		
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -50 \ \mu A$		3.0	2.9	3.0	—	2.9	—		
High-level output					4.5	4.4	4.5	_	4.4	_	V	
voltage			$I_{OH} = -4 \text{ mA}$		3.0	2.58	_		2.48		v	
			$I_{OH} = -24 \text{ mA}$		4.5	3.94	—	—	3.80	—		
			$I_{OH} = -75 \text{ mA}$	(Note)	5.5	_	—	_	3.85	_		
	V <sub>OL</sub>	Vin = Vih			2.0	—	0.0	0.1	—	0.1		
			$I_{OL}=50~\mu A$		3.0	—	0.0	0.1	—	0.1		
Low-level output voltage					4.5	_	0.0	0.1	_	0.1	v	
			$I_{OL} = 12 \text{ mA}$		3.0		—	0.36		0.44	v	
			$I_{OL} = 24 \text{ mA}$		4.5	—	—	0.36	—	0.44		
			$I_{OL} = 75 \text{ mA}$	(Note)	5.5	_	—	_	_	1.65		
Input leakage current	lın	$V_{IN} = V_{CC} \text{ or } GND$			5.5	—	—	±0.1		±1.0	μA	
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND			5.5	_	_	4.0		40.0	μA	

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

#### AC Characteristics (C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 $\Omega$ , input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay time	t <sub>pLH</sub>	_	$\textbf{3.3}\pm\textbf{0.3}$		7.6	13.0	1.0	15.0	ns
	t <sub>pHL</sub>		$5.0\pm0.5$		6.1	8.6	1.0	9.9	
Input capacitance	C <sub>IN</sub>	—		_	5	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub> (Note)	_			70		_		pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

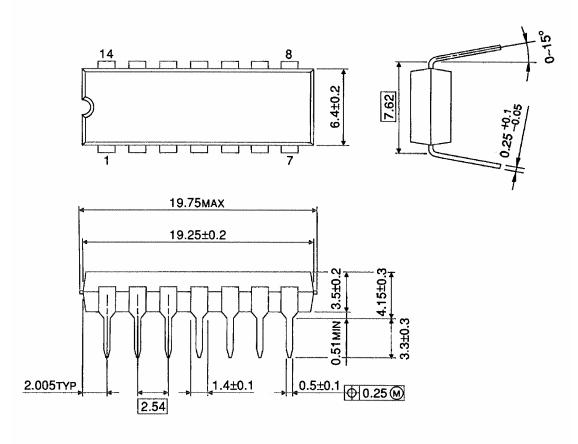
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$  (per gate)

# Package Dimensions

DIP14-P-300-2.54

Unit : mm

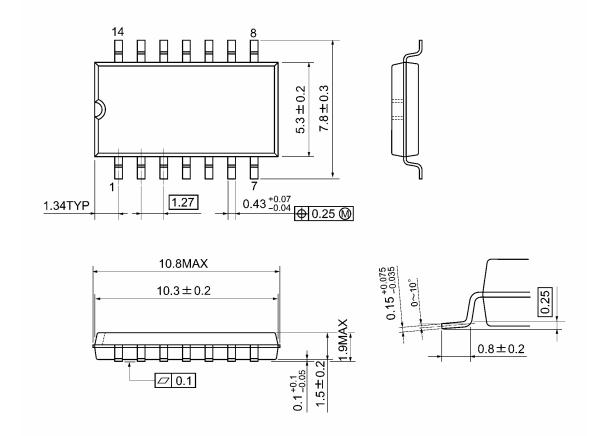


Weight: 0.96 g (typ.)

# **Package Dimensions**

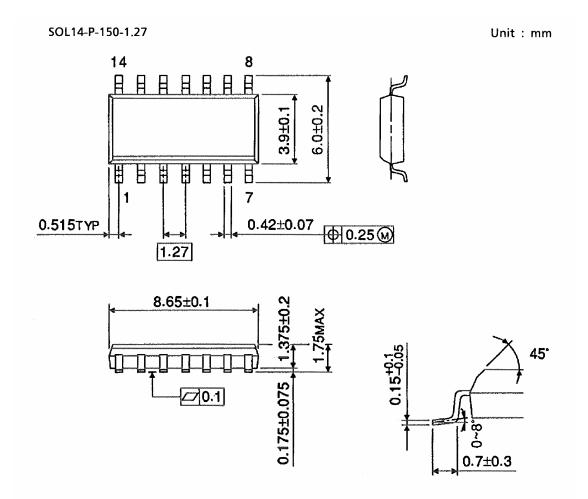
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

# Package Dimensions (Note)



Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

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20070701-EN GENERAL

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